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2-Alkyl-5-thienyl-Substituted Benzo[1,2-b:4,5-b']dithiophene-Based Donor Molecules for Solution-Processed Organic Solar Cells

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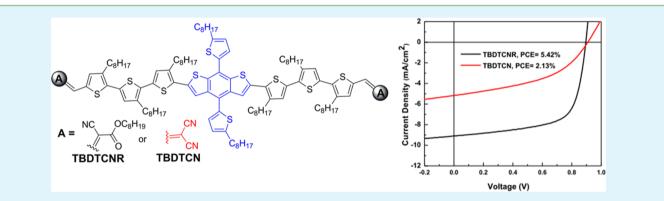
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Supporting Information



ABSTRACT: In this study, we have strategically designed and convergently synthesized two novel, symmetrical, and linear A– D–A-type π -conjugated donor molecules (TBDTCNR, TBDTCN), each containing a planar electron-rich 2-octylthiene-5-ylsubstituted benzodithiophene (TBDT) unit as the core, flanked by octylthiophene units and end-capped with electron-deficient cyanoacetate (CNR) or dicyanovinyl (CN) units. We thoroughly characterized both of these materials and investigated the effects of the end groups (CNR, CN) on their optical, electrochemical, morphological, and photovoltaic properties. We then fabricated solution-processed bulk heterojunction organic solar cells incorporating TBDTCNR and TBDTCN. Among our tested devices, the one containing TBDTCNR and [6,6]-phenyl-C₆₁-butyric acid methyl ester in a 1:0.40 ratio (w/w) exhibited the highest power conversion efficiency (5.42%) with a short-circuit current density (J_{sc}) of 9.08 mA cm⁻², an open circuit voltage (V_{oc}) of 0.90 V, and an impressive fill factor (FF) of 0.66 under AM 1.5G irradiation (100 mW cm⁻²). The FFs of these solutionprocessed small-molecule organic solar cells (SMOSCs) are outstanding when compared with those recently reported for benzodithiophene (BDT)-based SMOSCs, because of the high crystallinity and excellent stacking properties of the TBDT-based compounds.

KEYWORDS: solution-processed small-molecule, donor—acceptor, organic solar cells, power conversion efficiency, benzo[1,2-b:4,5-b']dithiophenes, external quantum efficiency

1. INTRODUCTION

Solution-processed polymer solar cells (PSCs) are emerging as promising alternatives to silicon-based solar cells; they provide enormous benefits as a result of their low cost, amenability, high-throughput roll-to-roll processing, and ready structural modifications.^{1–5} Recently, tremendous research efforts have been devoted to the development of π -conjugated small molecules for use in bulk heterojunction (BHJ) solar cells, the power conversion efficiencies (PCEs) of which have dramatically increased to over 8%.^{6,7} Although the PCEs of solution-processed small molecule organic solar cells (SMOSCs) have not matched those achieved by PSCs, their

many advantages ready synthesis, high purity and crystallinity, well-defined molecular structures, lack of end group contaminants, high mobility, and batch-to-batch consistency cannot be ignored.^{8–10} Some spectacular results have been demonstrated recently for SMOSCs, suggesting that they might soon become better alternatives to PSCs in the quest to meet global energy challenges.^{68,9} Nevertheless, research into SMOSCs requires much further attention if we are to solve their shortcomings

Received: June 10, 2013 Accepted: September 3, 2013 Published: September 3, 2013 namely, low fill factors (FFs), poor film quality and morphology, and unbalanced charge transport relative to that of PSCs.^{11,12} To overcome these challenges, it will be necessary to develop novel alternating donor–acceptor (D–A) building blocks using a design strategy similar to that for PSCs.

Substantial progress has been made in the fabrication of SMOSCs incorporating small molecules featuring different D and A units, including oligothiophene,¹³ triphenylamine,¹⁴ dithienosilole,⁶ benzodithiophene,⁷ benzotrithiophene,¹⁵ benzothiadiazole,¹⁶ diketopyrrolopyrole,¹⁷ cyanoacetates,¹⁸ dicyanovinyl,¹⁹ and rhodanine⁷ moieties, in novel molecular frameworks (e.g., D-A-D, A-D-A, D-A-A, D-A-D-A-D). Because of their efficient light harvesting, face-to-face $\pi - \pi$ stacking, structural versatility, and superior charge transport behavior and solar cell performance, fused thiophene-based A-D-A architectures containing cyanoacetate (CNR) and dicyanovinyl (CN) units have recently gained considerable attention.¹⁸⁻²¹ Indeed, when Chen and coworkers prepared SMOSCs incorporating small molecules featuring benzodithiophene (BDT)-based moieties as the central-donating core and end-capped with CNR groups, they achieved PCEs of up to 5.54%.¹ ⁸ Bäuerle and coworkers recently reported several oligothiophenes and alkylthiophenes end-capped with CN units that they use to prepare vacuum- and solution-processed solar cells displaying impressive performance.^{19,21} Chen and coworkers also reported another successful SMOS incorporating a planar molecule featuring a BDT unit as the electron-donating core surrounded by alkylthiophene units and terminated with rhodanine as the electron acceptor that displayed a PCE of 8.12%;⁷ here, the lateral modification of the BDT core with alkylthiophene units extended the electron donating capability and solubility of the π -conjugated moiety. Hou and Yang et al. prepared 2-alkyl-5-thienyl-substituted benzo[1,2-b:4,5-b']dithiophenes (TBDTs) coplanar, $\pi - \pi$ stacking, high-mobility, sulfur-rich, electron-donating alternatives to BDT that provided SMOSCs displaying excellent performance relative to PSCs.²² Moreover, TBDT-type compounds exhibit low-energy highest occupied molecular orbitals (HOMOs) potentially providing high open circuit voltages and energy levels of lowest unoccupied molecular orbitals (LUMOs) that can be manipulated effectively through the use of various acceptors.⁷

Herein, we report the design and synthesis of two small molecules (TBDTCNR, TBDTCN), each containing TBDT as the central electron donor unit flanked by octylthiophene units and end-capped with CNR or CN acceptors. The nature of the acceptor end group affects the intermolecular interactions of TBDTCNR and TBDTCN and, thereby, their bulk properties, including their optical, electrochemical, X-ray diffraction (XRD), and photovoltaic properties. Among our tested systems, the best BHJ solar cell device incorporating a blend of TBDTCNR and [6,6]phenyl-C₆₁-butyric acid methyl ester (PC₆₁BM) at a ratio of 1:0.4 delivered the highest PCE (5.42%).

2. EXPERIMENTAL SECTION

2.1. Fabrication and Characterization of Organic Solar Cells (OSCs). The solution-processed small-molecule BHJ solar cells featured a thin film of the active layer, a blend of the donor (TBDTCNR or TBDTCN) and acceptor ($PC_{61}BM$) materials, sandwiched between a transparent anode (ITO) and a metal cathode. Prior to device fabrication, the ITO glasses ($1.5 \times 1.5 \text{ cm}^2$) were cleaned ultrasonically with detergent, deionized water, acetone, and isopropyl alcohol. After routine solvent cleaning, the ITO substrates

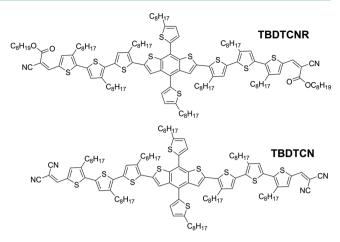


Figure 1. Chemical structures of TBDTCNR and TBDTCN.

were treated with UV ozone for 15 min and then spin-coated with the PEDOT:PSS layer (~30 nm) at 4000 rpm. The active layer solution, TBDTCNR/PC₆₁BM or TBDTCN/PC₆₁BM (8 mg mL⁻¹ for donor materials in CHCl₃), was then cast upon the modified ITO substrate. Thermal annealing treatment was performed at various temperatures from 75 to 125 °C for 30 min to pre-anneal the active layer. After preparing the active layer, Ca (30 nm) and Al (100 nm) were evaporated onto the active layer under vacuum (pressure = $<6 \times 10^{-6}$ Torr) through a shadow mask to form the cathodes. The active area of the devices was 0.1 cm². The active layer thickness was measured using an AlphaStep profilometer (Veeo, Dektak 150). The photovoltaic performance was characterized within a N2-filled glove box under an AM 1.5G filter (100 mW cm⁻²) using a Newport Oriel Solar Simulator (Thermal Oriel 1000W), as calibrated using a Si photodiode. All electric testing was performed within N2-filled glove boxes using an HP 4145C semiconductor parameter analyzer. EQEs were measured by comparing the photocurrent of a sample device and that of a standard Si device at various wavelengths of incident light. The light source was a 450 W Xe lamp (Oriel Instrument, model 6266) equipped with a water-based IR filter (Oriel Instrument, model 6123NS). The light output from the monochromator (Oriel Instrument, model 74100) was focused onto the PV devices.

2.2. Fabrication of Hole- and Electron-Only Devices. The configurations of the hole- and electron-only devices were ITO/ PEDOT:PSS/small molecule:PC₆₁BM/V₂O₅/Al and ITO/Cs₂CO₃/ small molecule:PC₆₁BM/Ca/Al, respectively. The electron and hole motilities were determined by fitting the plots of the dark *J*–*V* curves for single-carrier devices to the SCLC model.²⁴ The dark current was given by

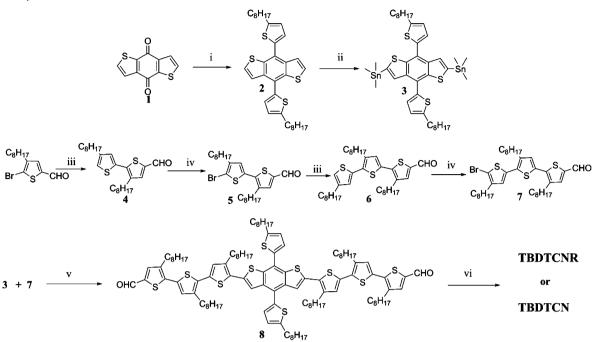
$$J = 9\varepsilon_0 \varepsilon_r \mu V^2 / 8L^3$$

where ε_r is the relative dielectric constant of the transport medium, ε_0 is the permittivity of free space, μ is the carrier mobility, and L is the device thickness.

3. RESULTS AND DISCUSSION

3.1. Synthesis and Thermal Properties. Scheme 1 presents the synthetic route we followed to prepare TBDTCNR and TBDTCN. We performed the syntheses of most of the intermediates (compounds 1-7) using slight modifications of procedures reported in the literature.^{18,21} Symmetrical Stille coupling of 3 and 7 yielded compound 8, which we subjected to Knoevenagel condensation to generate TBDTCNR and TBDTCN. Both TBDTCNR and TBDTCN were highly soluble in common organic solvents (e.g., CH_2Cl_2 , $CHCl_3$, and THF) and exhibited good thermal stability up to 365 °C under a N₂ atmosphere (Supporting Information Figure S3). The melting point of TBDTCNR and TBDTCN found to

Scheme 1. Synthesis of TBDTCNR and TBDTCN^a



"Reagents and conditions: (i) 2-octylthiophene, *n*-BuLi, THF, 1 h; then compound 1, 50 °C, 1 h; then $SnCl_2/HCl/H_2O$, 50 °C, 2 h; (ii) *n*-BuLi, THF, -78 °C, 1 h; then $SnMe_3Cl$; (iii) trimethyl(4-octylthien-2-yl)stannane, Pd(PPh₃)₄, toluene, reflux; (iv) NBS, CHCl₃/AcOH (1:1), 0 °C then RT overnight; (v) Pd(PPh₃)₄, toluene, reflux; (vi) CHCl₃, piperidine, octyl cyanoacetate, RT, 36 h; or CHCl₃, piperidine, malononitrile, RT, 36 h.

be 177 and 207 °C (Supporting Information Figure S3), respectively.

3.2. Optical Properties. Figure 2 displays normalized UVvis absorption spectra of dilute solutions of TBDTCNR and

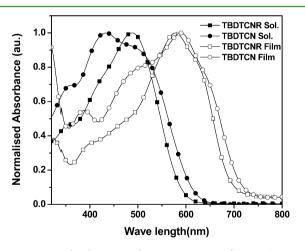


Figure 2. Normalized UV–vis absorption spectra of TBDTCNR and TBDTCN as dilute solutions in $CHCl_3$ and as thin films on glass surfaces at room temperature.

TBDTCN in CHCl₃ and of their solid films spin-coated onto glass substrates; Table 1 lists the normalized absorption maxima for both the solutions and solid films and their optical band gaps (E_{σ}^{opt}). In solution, both TBDTCNR and TBDTCN exhibited two characteristic bands: a shorter-wavelength absorbance arising from $\pi - \pi^*$ transitions and a longerwavelength band that we attribute to intramolecular charge transfer (ICT) between the electron-rich TBDT and electrondeficient (CNR or CN) segments.¹⁶ The absorption band of TBDTCNR in solution was located at 488 nm. In contrast, the absorption spectrum of TBDTCNR as a solid film exhibited localization of its transition and ICT bands, which overlapped to form a new broad band at 578 nm and a bathochromic shift of approximately 90 nm relative to that in solution, due to effective $\pi - \pi$ interactions.¹⁸ The absorption band of TBDTCN in solution and in the solid film appeared at 494 (shoulder) and 590 nm, respectively; again, the latter exhibited a bathochromic shift of approximately 96 nm relative to the former, as well as broadening of the ICT band as a result of strong $\pi - \pi$ interactions.^{13,25} The presence of highly electron withdrawing CN groups at both ends of the TBDT unit led to bathochromic shifts of 6 and 12 nm relative to the signals of the CNRpresenting TBDT derivative in solution and in the solid film,

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Table 1. Optical and Electrochemical Properties of TBDTCNR and TBDTCN

	solution ^a	solid film ^b	energy levels		band gaps ^d	
SM	$\lambda_{ m max,abs}~(m nm)$	$\lambda_{ m max,abs}~(m nm)$	$E_{\text{onset}}^{\text{ox}}$ (V)/HOMO ^c (eV)	$E_{\text{onset}}^{\text{red}}$ (V)/LUMO ^c (eV)	$E_{\rm g}^{\rm ec}$ (eV)	E_{g}^{opt} (eV)
TBDTCNR	488	578	1.05/-5.40	-0.72/-3.63	1.77	1.75
TBDTCN	433, 494	590	1.10/-5.45	-0.74/-3.61	1.84	1.72

^{*a*}In THF dilute solution. ^{*b*}Spin-coated from THF solution onto a glass surface. ^{*c*}E_{HOMO}/E_{LUMO} = $[-(E_{onset} - E_{onset}(FC/FC^*vsAg/Ag^*)) - 4.8]$ eV, where 4.8 eV is the energy level of ferrocene below the vacuum level and the formal potential $E_{onset}(FC/FC^*vsAg/Ag^*)$ is equal to 0.45 V. ^{*d*}Electrochemical band gap: $E_{g}^{opt} = E_{ox/Onset} - E_{red/Onset}$; optical band gap: $E_{g}^{opt} = 1240/\lambda_{edge}$.

respectively. We calculated the optical band gaps for TBDTCNR and TBDTCN, from the onsets of the signals in the absorption spectra of the thin films, to be 1.75 and 1.72 eV, respectively. The broad features in the absorption spectra of TBDTCNR and TBDTCN suggested that both compounds would be effective candidates for application in BHJ solar cells.

3.3. Electrochemical Properties. We used cyclic voltammetry (CV) to investigate the electrochemical properties of TBDTCNR and TBDTCN; Figure 3 presents their

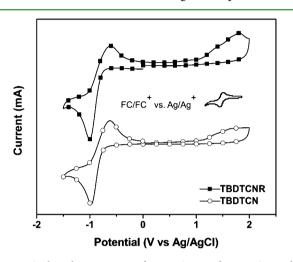


Figure 3. Cyclic voltammograms of TBDTCNR and TBDTCN as thin films (scan rate = 100 mV s^{-1}).

oxidation and reduction cyclic voltammograms and Table 1 summarizes the data. TBDTCNR and TBDTCN both underwent oxidation (p-doping), because of their electronrich TBDT units, in positive potential ranges and reduction (ndoping), because of their electron-poor CNR and CN units, in negative potential ranges.²⁶ The onset oxidation potentials (E_{ox}^{onset}) for TBDTCNR and TBDTCN were 1.05 and 1.10 V, respectively, while their onset reduction potentials (E_{red}^{onset}) were -0.72 and -0.74 V, respectively. We estimated the HOMO and LUMO energy levels from the oxidation and reduction potentials and the reference energy level of ferrocene (4.8 eV below the vacuum level) according to the equations²⁷

$$E_{\text{HOMO/LUMO}} = \left[-(E_{\text{onset}} - E_{\text{onset}(\text{FC/FC}^+\text{vsAg/Ag}^+)}) - 4.8 \right] \text{eV}$$

and

band gap =
$$E_{\text{onset}}^{\text{ox}} - E_{\text{onset}}^{\text{red}}$$

where the formal potential $E_{\text{onset}(\text{FC/FC}^+\text{vsAg/Ag}^+)}$ is equal to 0.45 V. Consequently, the calculated HOMO and LUMO energy levels for TBDTCNR were -5.40 and -3.63 eV, respectively, and those for TBDTCN were -5.45 and -3.61 eV, respectively. The electrochemical band gaps, calculated from the oxidation and reduction potentials, were approximately 1.77 eV for TBDTCNR and 1.84 eV for TBDTCN. TBDTCN possessed a relatively low HOMO energy level relative to that of TBDTCNR, due to its high onset oxidation potential resulting from the presence of its more highly electron deficient CN units.^{28,29} The LUMO energy levels of TBDTCNR and TBDTCN were dependent upon the strength of their accepting moieties.30 We anticipated that the low-lying HOMO energy levels of these two TBDT-based compounds would provide higher open circuit voltages (V_{0c}) for their BHJ solar cells incorporating $PC_{61}BM$ as an acceptor, because the value of V_{oc}

depends on the difference between the HOMO energy level of the donor and the LUMO energy level of the acceptor.¹⁹ The LUMO energy levels of TBDTCNR and TBDTCN (-3.63 and -3.61 eV, respectively) are positioned approximately 0.3 eV above the LUMO energy level of PC₆₁BM, thereby suggesting energetically favorable electron transfer from the donor units to the acceptor units.^{24,30} The electrochemical band gaps, which were in good agreement with the optical band gaps, were in the desirable range for organic photovoltaic applications.

3.4. Theoretical Calculation. We used density functional theory (DFT) to investigate the geometry and energy levels of TBDTCNR. Supporting Information Table S1 lists the HOMO and LUMO energy levels and the theoretical band gap of TBDTCNR that we determined from our DFT calculations of a single molecule in a vacuum. These values are in reasonable agreement with the experimental values determined using CV. We attribute the slight discrepancy in the theoretical and experimental band gaps to the presence of solvent molecules in the CV experiment. Supporting Information Figure S6 displays the relaxed molecular structure (upper panel), the HOMO electron density (middle panel), and the LUMO electron density (lower panel) of TBDTCNR. The HOMO orbital has its greatest contributions from the central TBDT and neighboring thiophene rings, whereas the LUMO orbital has a significant contribution from the side thiophene rings and the capped CNR groups, indicating a typical A-D-A architecture. We suspect that when the system is oxidized, an electron is removed from the central TBDT ring, but when the system is reduced, the electron has a probability of appearing in the side thiophene rings or the CNR groups.

3.5. XRD. To investigate the molecular order and packing in the films of these materials, we recorded XRD patterns of TBDTCNR and TBDTCN after they had been spin-coated from CHCl₃. Figure 4 reveals that the solid films of TBDTCNR

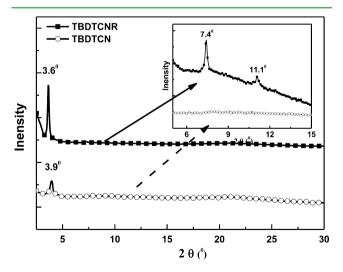


Figure 4. XRD patterns of TBDTCNR and TBDTCN films spincoated from $CHCl_3$. Inset: Expanded view of the pattern for TBDTCNR and TBDTCN in the range 6–14 Å.

and TBDTCN were highly ordered because of their crystalline behavior. The XRD patterns for the solid films of TBDTCNR and TBDTCN exhibited similar strong first-order (100) diffraction peaks at values of 2θ of 3.6 and 3.9°, respectively, corresponding to d_{100} -spacings of 23.0 and 22.6 Å, respectively. The d_{100} -spacing is the distance between the main conjugated chains of the small molecules, separated by their side chains;

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our solution-processed small molecules feature many alkyl side chains around the main chain, leading to the highly intense first-order (100) diffraction peaks, which were similar to those observed for poly(3-octylthiophene) (P3OT, 20.1 Å) and recently reported some BDT based SMOSCs.^{7,18,31} The second-order (200) and third-order (300) diffraction peaks for the thin film of TBDTCNR appeared at values of 2θ of 7.4° and 11.1°, respectively, corresponding to a d_{200} -spacing of 11.0 Å and a d_{300} -spacing of 7.0 Å. Relative to the signals for the solid film of TBDTCN, the second-order (200) and third-order (300) diffraction peaks were almost invisible. This result implies that TBDTCNR undergoes strong $\pi - \pi$ stacking of its main chain and provides a well-organized lamellar structure.³¹ From the XRD data, we conclude that the crystallinity of TBDTCNR is greater than that of TBDTCN, potentially benefiting the transport of carriers and enhancing the shortcircuit current after its incorporation into organic solar cell devices. The strong $\pi - \pi$ stacking ability of TBDTCNR would presumably remain after its incorporation into the active layer of a device, potentially providing a high FF.

3.6. Photovoltaic Properties. We fabricated BHJ solar cells after spin-coating blends from CHCl₃ solutions at various small molecule to PC₆₁BM ratios, with a device structure of indium tin oxide (ITO)/poly(3,4-ethylenedioxythiophene):polystyrenesulfonate (PEDOT:PSS)/small molecule:PC₆₁BM/ Ca/Al. We examined the effects of the spin rate (from 1000 to 4000 rpm) and the pre-annealing temperature on the device performance (Supporting Information Figure S7 and Table S2), which we measured under AM 1.5 illumination (100 mW cm⁻²). Figure 5 presents the detailed current density-voltage (I-V) characteristics of TBDTCNR and TBDTCN; Table 2 summarizes the corresponding device parameters. The devices incorporating TBDTCNR and TBDTCN displayed high values of $V_{\rm oc}$ (~0.9 V), because of their low-lying HOMO energy levels, but their optimized PCEs were obtained at different small molecule to PC61BM ratios. A photovoltaic device containing TBDTCNR and PC₆₁BM at a blend ratio of 1:0.25 (w/w) exhibited a value of V_{oc} of 0.90 V, a value of J_{sc} of 6.35 mA cm⁻², a FF of 65%, and a PCE of 3.69%; at a weight ratio of 1:0.4, these values were improved to 0.90 V, 9.08 mA cm⁻², 66%, and 5.42%, respectively. Although the cell efficiency decreased upon further increasing the amount of $PC_{61}BM$, the FFs of cells remain above 55%. This high performance suggests that TBDTCNR not only was highly miscible with $PC_{61}BM$ to form nanoscale phase separations at the D-A interfaces for dissociation of the generated excitons by minimized recombination but also displayed good $\pi - \pi$ stacking ability and enhance the charge transport and the carrier collection efficiency, resulting in reasonable photogenerated currents and FFs. These devices incorporating TBDTCNR provide the one of the best FFs (66%) among all recently reported BDTbased solution-processable small-molecule solar cells prepared without additives or thermal treatment.^{7,10–12,18,32,33} Moreover, various recent works reported by Chen et al. obtained the highest FF 72% in SMOSCs after addition of additives or without additives or thermal treatment or modified device architecture.^{7,34} On the other hand, the PCE of the photovoltaic device incorporating TBDTCN and PC₆₁BM at a weight ratio of 1:0.4 was 1.56%, with value of $V_{\rm oc}$ of 0.91 V, a value of J_{sc} of 3.69 mA cm⁻², and a FF of 47%; the optimal PCE (2.13%) resulted at a weight ratio of 1:0.6, with values of V_{oc} J_{sc} and FF of 0.91 V, 5.17 mA cm⁻², and 46%, respectively. The cell performance when using TBDTCN was lower than that

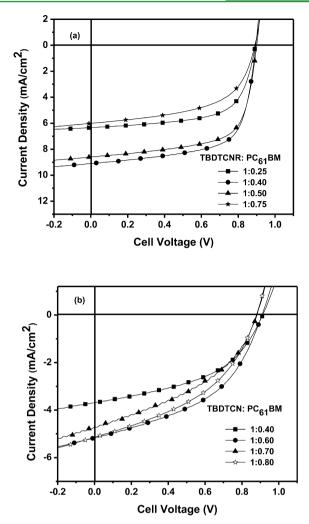


Figure 5. (a) J-V curves of BHJ solar cell devices incorporating blend ratios of TBDTCNR:PC₆₁BM (w/w) and (b) TBDTCN:PC₆₁BM (w/w).

Table 2. Photovoltaic Properties of TBDTCNR and TBDTCN

SM:PC ₆₁ BM	ratio	$V_{\rm oc}~({\rm V})$	$J_{\rm sc}~({\rm mA~cm^{-2}})$	FF (%)	PCE (%)
TBDTCNR	1:0.25	0.90	6.35	65	3.69
	1:0.40	0.90	9.08	66	5.42
	1:0.50	0.90	8.60	66	5.14
	1:0.75	0.90	6.01	55	2.98
TBDTCN	1:0.40	0.91	3.69	47	1.56
	1:0.60	0.91	5.17	46	2.13
	1:0.70	0.88	5.14	43	1.93
	1:0.80	0.88	4.70	41	1.69

when using TBDTCNR because of its lower crystallinity and solubility. Interestingly, increasing the concentration of $PC_{61}BM$ in the blend films of TBDTCNR (from 1:0.4 to 1:0.75) and TBDTCN (from 1:0.60 to 1:0.75) had a strong impact on the values of J_{sc} , but less on the values of V_{oc} (Table 1), which is related to the nature of the materials as well as in the morphology.²⁵

Figure 6 reveals the external quantum efficiencies (EQEs) of the optimized devices based on TBDTCNR:PC₆₁BM (1:0.4) and TBDTCN:PC₆₁BM (1:0.6) under monochromatic light; their performances at other weight ratios are presented in the

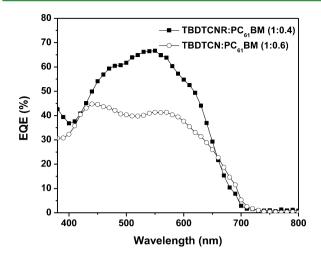


Figure 6. EQE curves of BHJ solar cell devices incorporating TBDTCNR:PC₆₁BM (1:0.4, w/w) and TBDTCN:PC₆₁BM (1:0.6, w/w) blends (optimized weight ratios).

Supporting Information (Figure S13). All of the devices exhibited photoresponses ranging from 380 to 700 nm, consistent with the absorption spectra. The maximum EQE reached 67% at 550 nm for the device containing TBDTCNR and PC₆₁BM at a weight ratio of 1:0.4 and resulted in a maximum value of J_{sc} of 9.08 mA cm⁻² (the calculated value of $J_{\rm sc}$ from the integrated EQE spectrum was 8.95 mA cm⁻²). This high EQE indicates that the BHJ film based on TBDTCNR could efficiently dissociate excitons and extract charge carriers. The corresponding devices incorporating TBDTCNR:PC₆₁BM at weight ratios of 1:0.25, 1:0.50, and 1:0.75 provided lower EQEs (51%, 64%, and 47%, respectively, Supporting Information Figure S13a) obtained at lower values of J_{sci} because of imbalances in the hole and electron mobilities and unfavorable morphologies (Figure 7), as we discuss below. In contrast, the EQE responses, values of J_{sc} and PCEs of the devices incorporating TBDTCN were all lower than those incorporating TBDTCNR. The highest EQE (Figure 6) from the device based on TBDTCN and PC₆₁BM was 41% at 550 nm, obtained at a weight ratio of 1:0.6; we attribute this relatively low value to TBDTCN's lower crystallinity (see XRD, Figure 4), which is associated with lower degree of charge extraction.

Atomic force microscopy (AFM) can provide useful information about D-A blend films, such as their miscibility, distributions, and interpenetrating network structures. To understand the differences in device performance when using TBDTCNR and TBDTCN as donors, we used AFM to investigate the morphologies of their pristine and optimized blend films (Figure 7). The pristine films of TBDTCNR and TBDTCN had root mean square roughnesses $(R_{\rm rms})$ of 8.91 and 4.04 nm, respectively, with the grain size of the former being larger than that of the latter. These features indicate that the stacking properties of TBDTCNR are better than those of TBDTCN, consistent with the XRD data (see Figure 4). The blend films of TBDTCNR/PC $_{61}$ BM (wt. ratio 1:0.4) and TBDTCN/PC₆₁BM (wt. ratio 1:0.6) exhibited good film formation, with smooth surfaces lacking any further aggregation; these blend film morphologies, with values of $R_{\rm rms}$ of 1.54 and 0.85 nm, respectively, were quite different from those of their pristine films. The AFM image of the TBDTCNR/ PC61BM blend film revealed that TBDTCNR has good

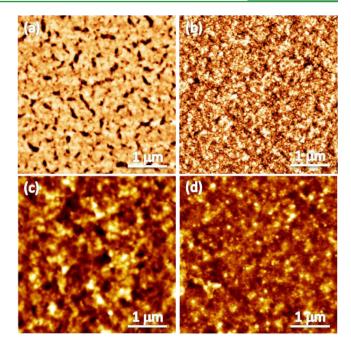


Figure 7. Tapping-mode AFM phase images of blend films cast from $CHCl_3$ solutions for (a, b) TBDTCNR:PC₆₁BM at weight ratios of (a) 1:0 and (b) 1:0.4 and (c, d) TBDTCN:PC₆₁BM at weight ratios of (c) 1:0 and (d) 1:0.6.

miscibility with PC61BM and that an optimized nanoscale phase separation had formed. Transmission electron microscopy (TEM) images were recorded both pristine films of TBDTCNR and the blend film TBDTCNR/PC₆₁BM (wt. ratio 1:0.4) and presented in Supporting Information Figure S10. The dark and bright regions in the TEM image can be attributed PC₆₁BM and TBDTCNR domains, respectively. A well-connected inter penetrating network of TBDTCNR with nanoscale phase separations were observed from the TEM image of the blend film TBDTCNR/PC₆₁BM (wt. ratio 1:0.4) compared to the pristine films of TBDTCNR. Nanoscale phase separation not only provides a large heterojunction interface for exciton dissociation but also efficient percolation channels for transporting the carriers to their respective electrodes, thereby improving the carrier extraction efficiency.¹² In contrast, TBDTCN was poorly miscible with PC₆₁BM, resulting in a lower-area heterojunction interface for exciton dissociation and, thereby, the generation of a low photocurrent.

The hole $(\mu_{\rm h})$ and electron $(\mu_{\rm e})$ mobilities of TBDTCNR/ PC₆₁BM at various weight ratios and of the optimized blend of TBDTCN/PC₆₁BM (1:0.60), as measured using the space charge limited current (SCLC) model, are plotted in Supporting Information Figures S11 and S12, respectively. Supporting Information Table S3 summarizes the values of $\mu_{\rm h}$ and μ_{e} for TBDTCNR and TBDTCN blended with PC₆₁BM. The values of $\mu_{\rm h}$ and $\mu_{\rm e}$ of the device containing TBDTCNR:PC₆₁BM at a weight ratio of 1:0.40 were 1.72 \times 10^{-4} and 1.51×10^{-4} cm² V⁻¹ s⁻¹, respectively, providing the most-balanced μ_e/μ_h ratio (0.88). The less-balanced μ_e/μ_h ratios for the device incorporating TBDTCNR:PC61BM at other blending weight ratios (1:0.25, 1:0.50, or 1:0.75) led to their lower values of J_{sc} and PCE. On the other hand, the optimized device incorporating TBDTCN:PC₆₁BM (1:0.60), provided values of $\mu_{\rm h}$ and $\mu_{\rm e}$ of 1.21 \times 10⁻⁴ and 9.73 \times 10⁻⁵ cm² V⁻¹ s⁻¹ and, therefore, a μ_e/μ_h ratio of 0.80 (Supporting Information Table S3). The values of μ_h and μ_e of the device

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based on TBDTCN/PC₆₁BM were roughly half of those of the corresponding device based on TBDTCNR/PC₆₁BM; as a result, the former device exhibited lower values of $J_{\rm sc}$ (5.17 mA cm⁻²) and PCE. We conclude that the device containing TBDTCNR and PC₆₁BM at a weight ratio of 1:0.40 exhibited the highest values of $J_{\rm sc}$ (9.05 mA cm⁻²), and FF which can be attributed to higher EQE response and good molecular packing in the active layers (XRD shown in Figure 4), superior charge transport properties, respectively, relative to those of all of the other tested devices.

4. CONCLUSIONS

We have synthesized TBDTCNR and TBDTCN two π conjugated small molecules having A-D-A architectures based on TBDT as the central donating core and modified with different end groups and correlated their photophysical and photovoltaic properties. These TBDT-based species possessed deep HOMO energy levels and provided devices exhibiting good values of V_{oc}. TBDTCNR showed not only good packing in the solid state but also superior charge transport properties and favorable nanoscale morphology relative to TBDTCN and thus pronounced to the higher PCE values. Among our tested systems, a photovoltaic device containing a blend TBDTCNR and PC₆₁BM at a weight ratio of 1:0.4 provided the highest PCE (5.42%), with high values of V_{oc} (0.90 V) and J_{sc} (9.08 mA cm^{-2}) and a notable FF (66%); this performance is comparable with that reported recently for BDT-containing π -conjugated small molecules. Further engineering of the molecular structure and optimization of the morphology, and variation of the acceptor moieties, are currently underway in our laboratory in the quest to boost device efficiencies. Such outstanding photovoltaic behavior suggests that SMOSCs might soon become majorly competitive with their polymeric counterparts.

ASSOCIATED CONTENT

Supporting Information

¹HNMR spectra, ¹³CNMR spectra, TGA and DSC curves, AFM height images, synthesis details, characterization, DFT calculations AFM, TEM images of the blends and transfer curves. This materials are available free of charge via the Internet at http://pubs.acs.org.

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Author Contributions

D.P. and T.-Y.H. contributed equally to this paper: D.P. was responsible for the synthesis of the solution-processable small molecules, and T.-Y.H. was responsible for determining the material characteristics and fabricating the devices.

Notes

The authors declare no competing financial interest.

ACKNOWLEDGMENTS

We thank the National Science Council of Taiwan (NSC 100-2120-M-009-004, 101-2120-M-009-001, and 101-2221-E-001-010) and the Thematic Project of Academia Sinica, Taiwan (AS-100-TP-A05), for financial support.

REFERENCES

- (1) Li, G.; Zhu, R.; Yang, Y. Nat. Photonics 2012, 6, 153.
- (2) Gendron, D.; Leclerc, M. Energy Environ. Sci. 2011, 4, 1225.

- (3) Facchetti, A. Chem. Mater. 2010, 23, 733.
- (4) Cheng, Y. J.; Yang, S. H.; Hsu, C. S. *Chem. Rev.* 2009, 109, 5868.
 (5) Chen, H.-C.; Chen, Y.-H.; Liu, C.-C.; Chien, Y.-C.; Chou, S.-W.; Chou, P. -T. *Chem. Mater.* 2012, 24, 4766.
- (6) Kyaw, A.K. K.; Wang, D. H.; Gupta, V.; Zhang, J.; Chand, S.; Bazan, G. C.; Heeger, A. J. Adv. Mater. 2013, 25, 2397.
- (7) Zhou, J.; Zuo, Y.; Wan, X.; Long, G.; Zhang, Q.; Ni, W.; Liu, Y.; Li, Z.; He, G.; Li, C.; Kan, B.; Li, M.; Chen, Y. *J. Am. Chem. Soc.* **2013**,
- 135, 8484.
 (8) Lin, Y. Z.; Li, Y. F.; Zhan, X. W. Chem. Soc. Rev. 2012, 41, 4245.
- (9) Mishra, A.; Bäuerle, P. Angew. Chem., Int. Ed. 2012, 51, 2020.

(10) Sun, Y.; Welch, G. C.; Leong, W. L.; Takacs, C. J.; Bazan, G. C.; Heeger, A. J. Nat. Mater. 2012, 11, 44.

(11) Liu, Y.; Wan, X.; Wang, F.; Zhou, J.; Long, G.; Tian, J.; You, J.; Yang, Y.; Chen, Y. Adv. Energy Mater. 2011, 1, 771.

(12) Li, Z.; He, G.; Wan, X.; Liu, Y.; Zhou, J.; Long, G.; Zuo, Y.; Zhang, M.; Chen, Y. Adv. Energy Mater. 2012, 2, 74.

- (13) Fitzner, R.; Osteritz, E. M.; Mishra, A.; Schulz, G.; Reinold, E.; Weil, M.; Körner, C.; Ziehlke, H.; Elschner, C.; Leo, K.; Riede, M.; Pfeiffer, M.; Uhrich, C.; Bäuerle, P. J. Am. Chem. Soc. **2012**, *134*, 11064.
- (14) Sahu, D.; Tsai, C. -H.; Wei, H. -Y.; Ho, K. -C.; Chang, F. -C.; Chu, C. -W. J. Mater. Chem. 2012, 22, 7945.

(15) Patra, D.; Chiang, C. -C.; Chen, W. -A.; Wei, K.-H.; Wu, M. -C.; Chu, C. -W. J. Mater. Chem A. 2013, 1, 7767.

(16) Dutta, P.; Kim, J.; Eom, S. -E.; Lee, W. -H.; Kang, I. N.; Lee, S. -H. ACS Appl. Mater. Interfaces **2012**, *4*, 6669.

(17) Huang, J.; Zhan, C.; Zhang, X.; Zhao, Y.; Lu, Z.; Jia, H.; Jiang, B.; Ye, J.; Zhang, S.; Tang, A.; Liu, Y.; Pei, Q.; Yao, J. *ACS Appl. Mater. Interfaces* **2013**, *5*, 2033.

(18) Liu, Y.; Wan, X.; Wang, F.; Zhou, J.; Long, G.; Tian, J.; Chen, Y. Adv. Mater. 2011, 23, 5387.

(19) Haid, S.; Mishra, A.; Weil, M.; Uhrich, C.; Pfeiffer, M.; Bäuerle, P. Adv. Funct. Mater. **2012**, 22, 4322.

(20) Dutta, P.; Yang, W.; Lee, W. H.; Kang, I. N.; Lee, S. H. J. Mater. Chem. 2012, 22, 10840.

(21) Fitzner, R.; Reinold, E.; Mishra, A.; Osteritz, E. M.; Ziehlke, H.; Körner, C.; Leo, K.; Riede, M.; Weil, M.; Tsaryova, O.; Weiß, A.;

Uhrich, C.; Pfeiffer, M.; Bäuerle, P. Adv. Funct. Mater. 2011, 21, 897. (22) Huo, L.; Zhang, S.; Guo, X.; Xu, F.; Li, Y.; Hou, J. Angew. Chem., Int. Ed. 2011, 50, 9697.

- (23) Liu, Y.; Wan, X.; Wang, F.; Zhou, J.; Long, G.; Tian, J.; Chen, Y. Adv. Mater. 2011, 23, 5387.
- (24) Malliaras, G. G.; Salem, J. R.; Brock, P. J.; Scott, C. Phys. Rev. B 1998, 58, 13411.
- (25) Liu, Y.; Wan, X.; Yin, B.; Zhou, J.; Long, G.; Yin, S.; Chen, Y. J. Mater. Chem. 2010, 20, 2464.
- (26) Patra, D.; Ramesh, M.; Sahu, D.; Padhy, H.; Chu, C.-W.; Wei,
- K.-H.; Lin, H.-C. J. Polym. Sci., Part A: Polym. Chem. 2012, 50, 967.
- (27) Patra, D.; Ramesh, M.; Sahu, D.; Padhy, H.; Chu, C.-W.; Wei, K.-H.; Lin, H.-C. *Polymer* **2012**, *53*, 1219.
- (28) Bura, T.; Leclerc, N.; Fall, S.; Lévêque, P.; Heiser, T.; Retailleau, P.; Rihn, S.; Mirloup, A.; Ziessel, R. J. Am. Chem. Soc. **2012**, 134, 17404.
- (29) Patra, D.; Ramesh, M.; Sahu, D.; Padhy, H.; Kekuda, D.; Chu,
- C.-W.; Wei, K.-H.; Lin, H.-C. *Macromol. Chem. Phys.* **2011**, *212*, 1960. (30) Scharber, M. C.; Mühlbacher, D.; Koppe, M.; Denk, P.; Waldauf, C.; Heeger, A. J.; Brabec, C. J. *Adv. Mater.* **2006**, *18*, 789.
- (31) Chen, T. A.; Wu, X. M.; Rieke, R. D. J. Am. Chem. Soc. 1995, 117, 233.
- (32) Lee, O. P.; Yiu, A. T.; Beaujuge, P. M.; Woo, C. H.; Holcombe, T. W.; Millstone, J. E.; Douglas, J. D.; Chen, M. S.; Fréchet, J. M. J. *Adv. Mater.* **2011**, *23*, 5359.

(33) Cui, C.; Min, J.; Ho, C. -L.; Ameri, T.; Yang, P.; Zhao, J.; Brabec, C. J.; Wong, W. -Y. *Chem. Commun.* **2013**, *49*, 4409.

(34) He, G.; Li, Ž.; Wan, X.; Zhou, J.; Long, G.; Zhang, S.; Zhang, M.; Chen, Y. J. Mater. Chem. A 2013, 1, 1801.